NCE N-Channel Super Trench I Power MOSFET

Description

The NCEP3065QU uses **Super Trench I** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS(ON)}}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

Application

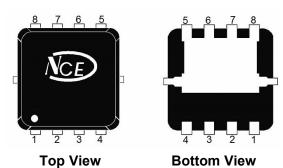
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

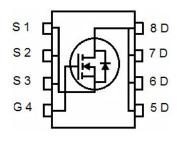
General Features

- V_{DS} =30V,I_D =65A
 - $R_{DS(ON)}$ =1.9m Ω (typical) @ V_{GS} =10V $R_{DS(ON)}$ =3.0m Ω (typical) @ V_{GS} =4.5V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 150 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!

DFN 3.3X3.3





Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP3065QU	NCEP3065QU	DFN3.3X3.3-8L	Ø180mm	-	5000

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	65	А
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	45.5	Α
Pulsed Drain Current	I _{DM}	260	А
Maximum Power Dissipation	P _D	55	W
Derating factor		0.44	W/℃
Single pulse avalanche energy (Note 1)	E _{AS}	500	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	$^{\circ}$

NCEP3065QU

Thermal Characteristic

Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics				,		•
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	30		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1	μA
		V _{GS} =±5V,V _{DS} =0V	-	-	±80	nA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics						•
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_{D}=250\mu A$	1.0	1.5	2.0	V
D : 0	-	V _{GS} =10V, I _D =20A	1.6	1.9	2.3	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =20A	2.5	3.0	3.6	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =20A		60	-	S
Dynamic Characteristics						•
Input Capacitance	C _{lss}	\/ 45\/\\ 0\/	-	2100	-	PF
Output Capacitance	Coss	$V_{DS}=15V, V_{GS}=0V,$	-	865	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	50	-	PF
Switching Characteristics (Note 2)						•
Turn-on Delay Time	t _{d(on)}		-	7.5	-	nS
Turn-on Rise Time	t _r	V_{DD} =15 V , I_D =20 A	-	4.0	-	nS
Turn-Off Delay Time	t _{d(off)}	$V_{GS}\text{=}10V, R_{G}\text{=}1.6\Omega$	-	37	-	nS
Turn-Off Fall Time	t _f		-	7.5	-	nS
Total Gate Charge	Qg)/ 45\/\ 004	-	34.8	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS}=15V, I_{D}=20A,$	-	6.2	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	5.1	-	nC
Drain-Source Diode Characteristics			·		'	
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =20A	-	-	1.2	V
Diode Forward Current	Is		-	-	65	Α
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C$, $I_F = I_S$	-	14	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/μs	-	21	-	nC

Notes:

- 1. EAS condition : Tj=25 $^{\circ}\text{C}$,V_DD=15V,V_G=10V,L=0.5mH,Rg=25 Ω
- 2. Guaranteed by design, not subject to production
- 3.These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsin k, assuming a maximum junction temperature of TJ(MAX)=150° C. The SOA curve provides a single pulse rating.



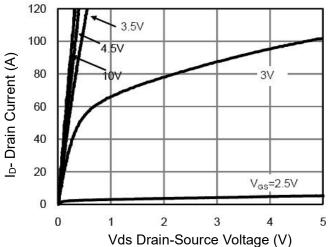


Figure 1 Output Characteristics

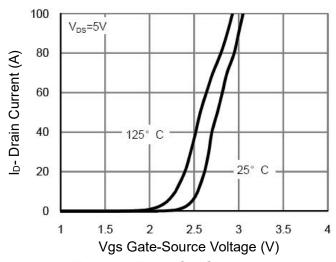


Figure 2 Transfer Characteristics

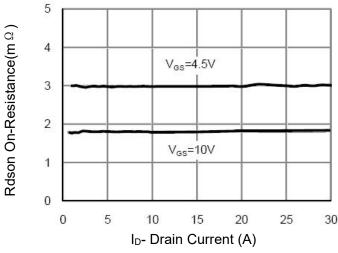


Figure 3 Rdson- Drain Current

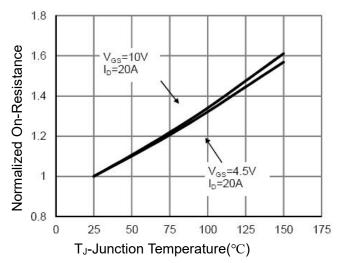


Figure 4 Rdson-Junction Temperature

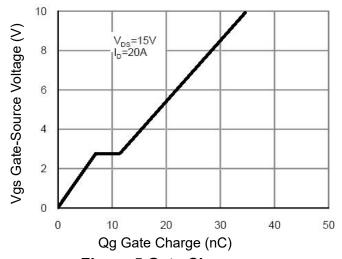


Figure 5 Gate Charge

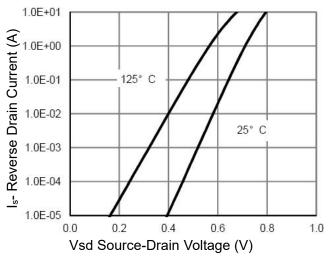
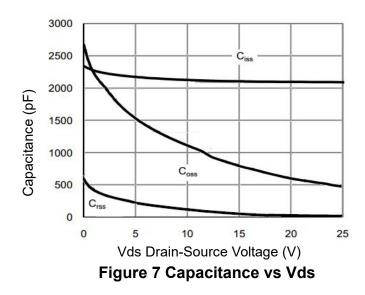


Figure 6 Source- Drain Diode Forward



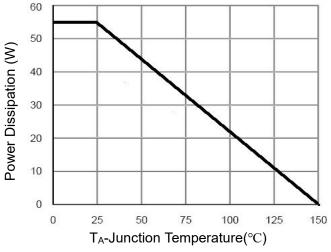
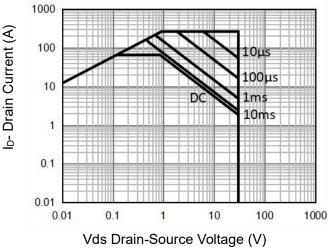


Figure 9 Power De-rating



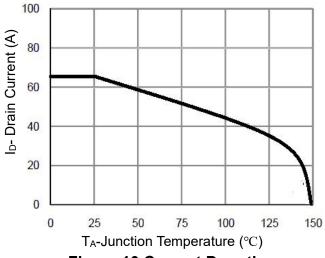


Figure 8 Safe Operation Area(Note 3)

Figure 10 Current De-rating

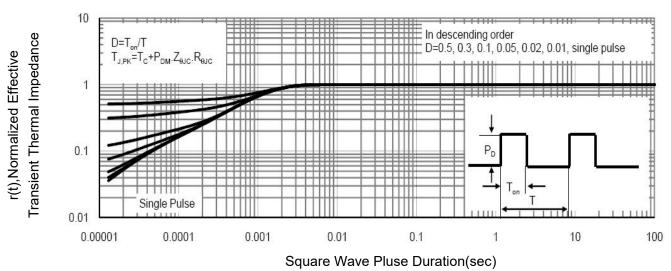
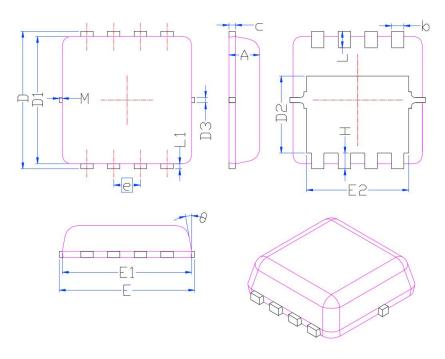


Figure 11 Normalized Maximum Transient Thermal Impedance

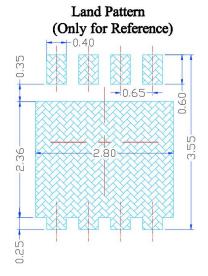
DFN3.3X3.3-8L Package Information



Note:

- 1. All Dimension Are In mm.
- Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs.
 Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
 Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.

MIN 0.70 0.25 0.10 0.25 0.00 0.78 0.10	NOM 0.75 0.30 0.15 3.35 3.10 1.88 0.13 3.20	MAX 0.80 0.35 0.25 3.45 3.20 1.98 3.30
0.25 0.10 0.25 0.00 0.78	0.30 0.15 3.35 3.10 1.88 0.13	0.35 0.25 3.45 3.20 1.98
0.10 3.25 2.00 2.78	0.15 3.35 3.10 1.88 0.13	0.25 3.45 3.20 1.98
3.25 2.00 2.78	3.35 3.10 1.88 0.13	3.45 3.20 1.98
.00 .78	3.10 1.88 0.13	3.20 1.98
.78	1.88 0.13	1.98
	0.13	
 3.10	U	3 30
3.10	3.20	3 30
		3.30
.00	3.15	3.20
2.39	2.49	2.59
	0.65BSC	
.30	0.39	0.50
.30	0.40	0.50
	0.13	
	10°	12°
		0.15



NCEP3065QU

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